

EL yield and charge gain in He/CF₄/isobutane mixtures

Rita Roque, Daniel Mano, Fernando Amaro, Cristina Monteiro, Joaquim Santos



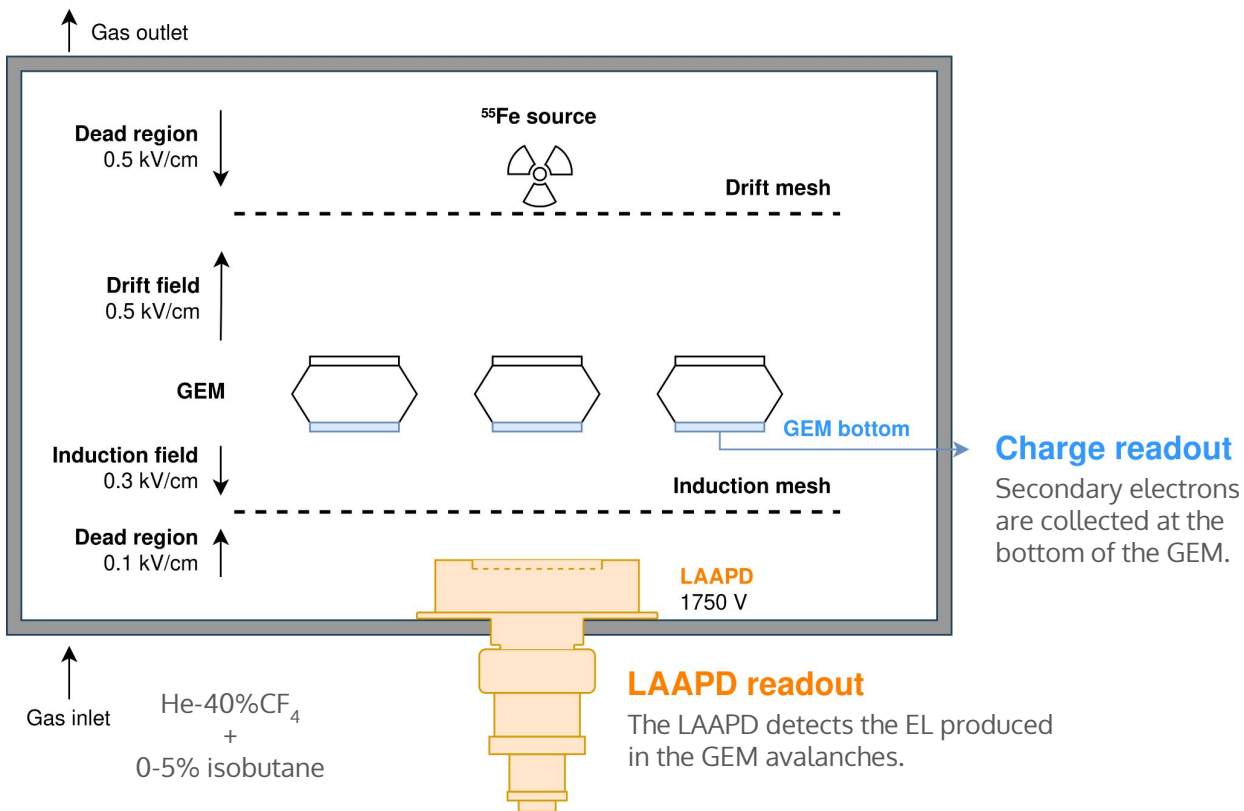
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Topics:

- Charge Gain
- EL yield
- Energy resolution

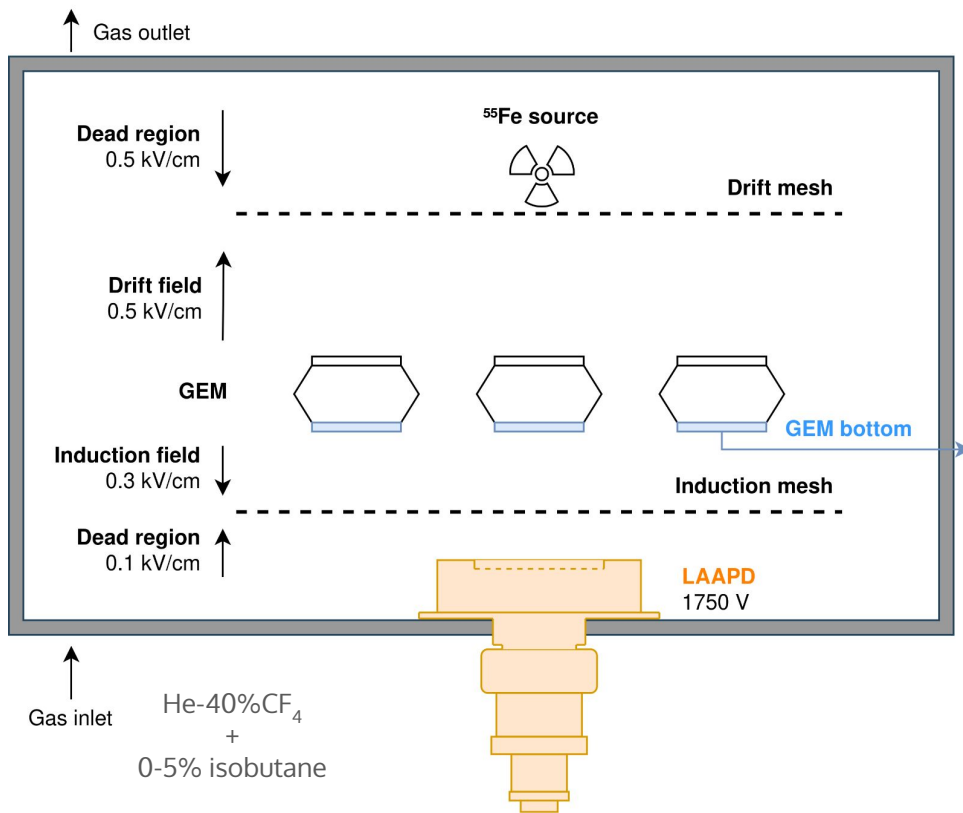
Experimental Setup

Detector Layout



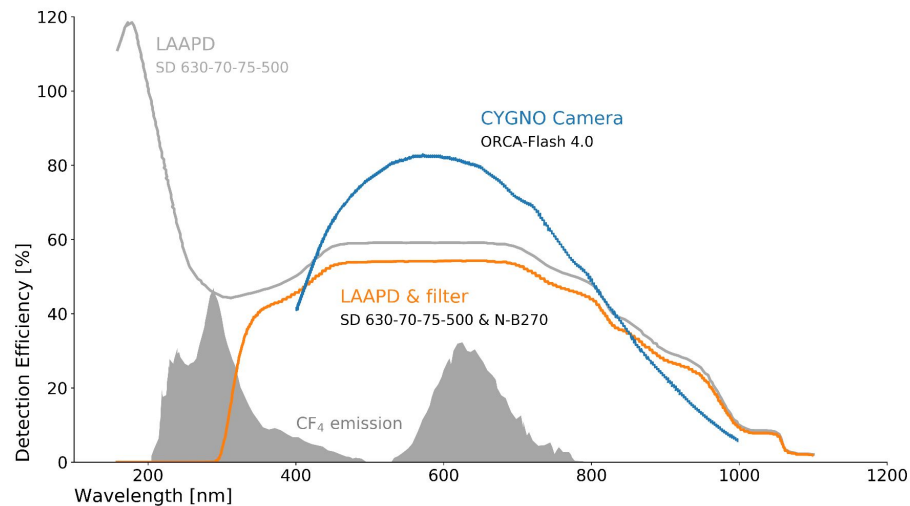
Experimental Setup

Detector Layout



Detector Components:

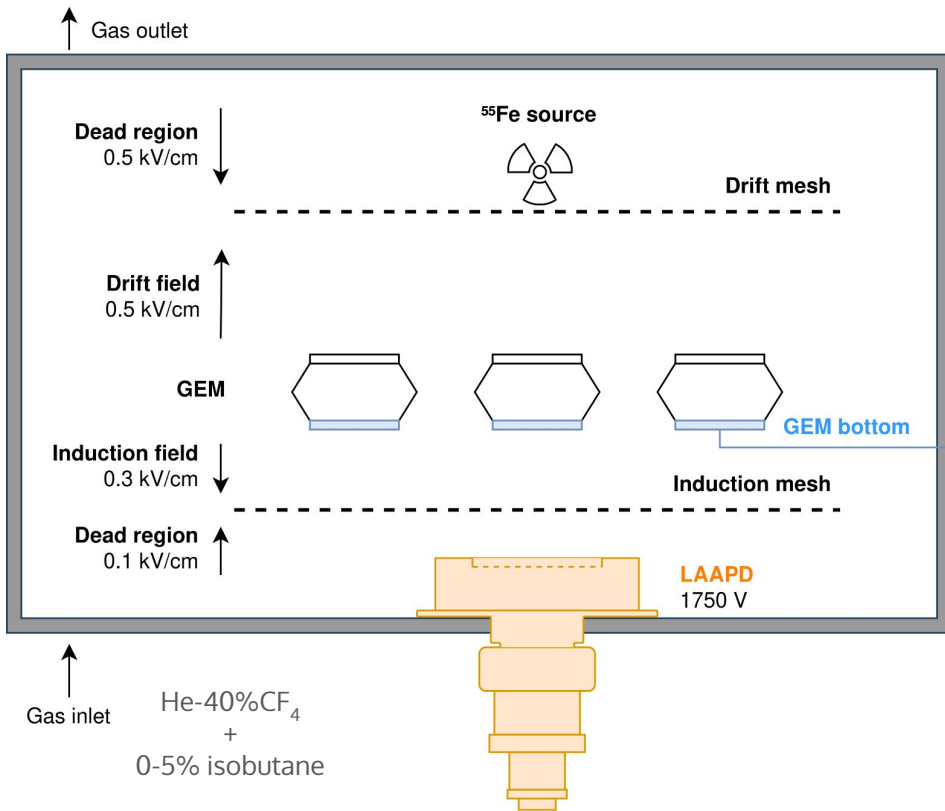
- **Meshes** with ~84% optical transparency;
- **Standard GEM** with 3 x 3 cm² area;
- **LAAPD**:
 - Active diameter: 16 cm;
 - Range: 150 - 1000 nm.



We will use a N-B270 glass window to filter out the UV component of the CF₄ EL.

Experimental Setup

Detector Layout



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- **LAAPD**:
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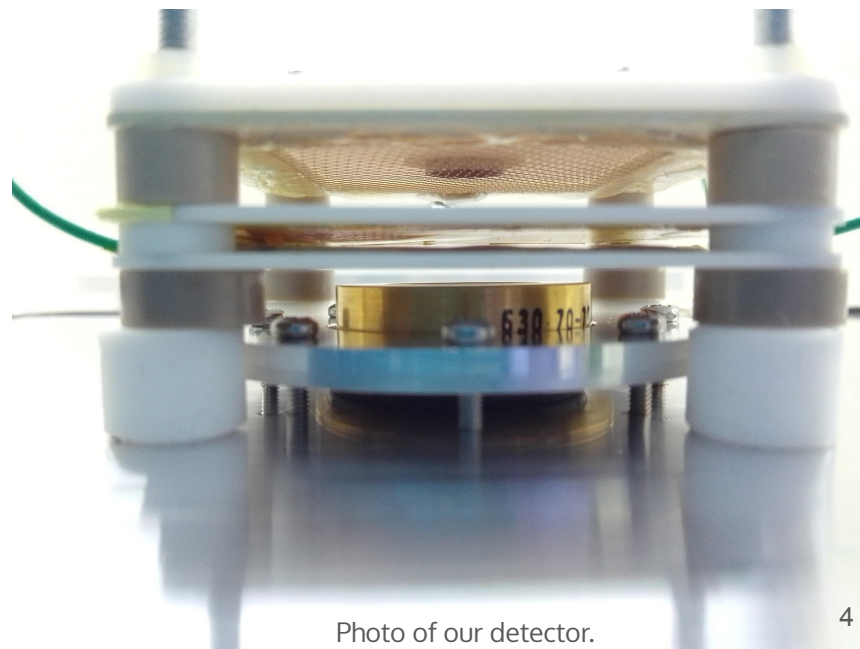
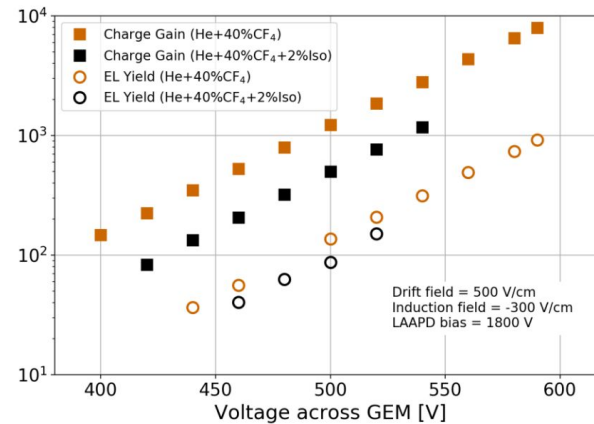


Photo of our detector.

Experimental Setup

Improvements in the gas flow

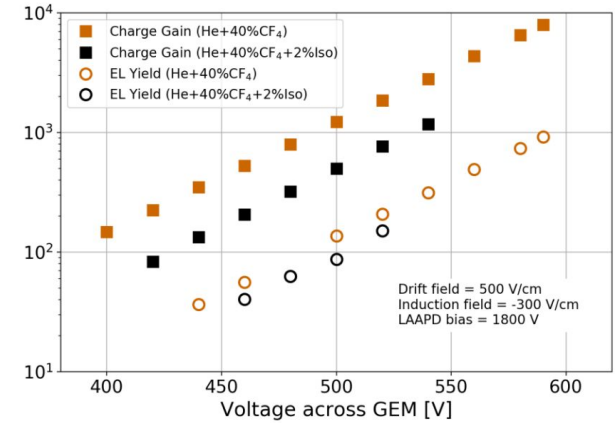


Results presented in 14/01/2021.

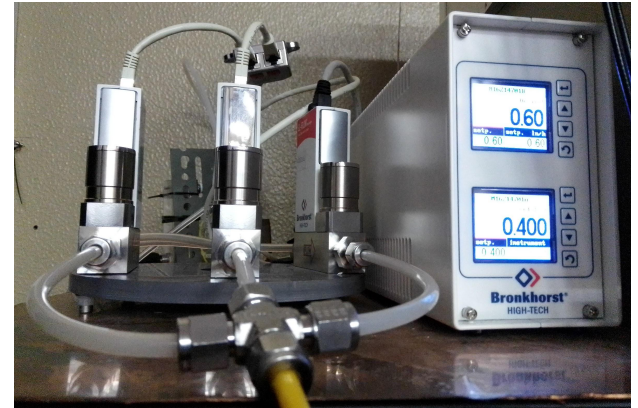
Experimental Setup

Improvements in the gas flow

- Reduced errors in the gas percentages by going from 1 L/h to 4 L/h.



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Gas flow controllers.

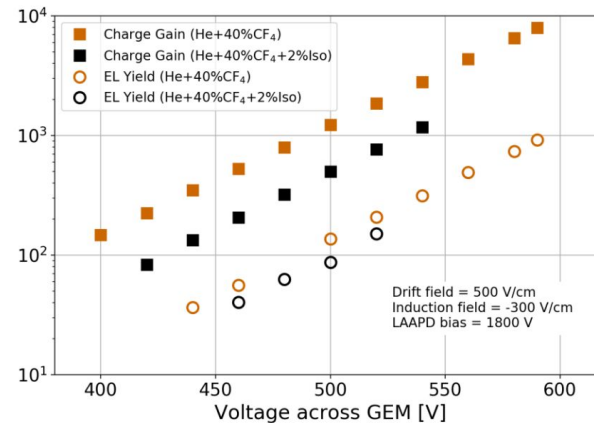
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Improvements in the gas flow

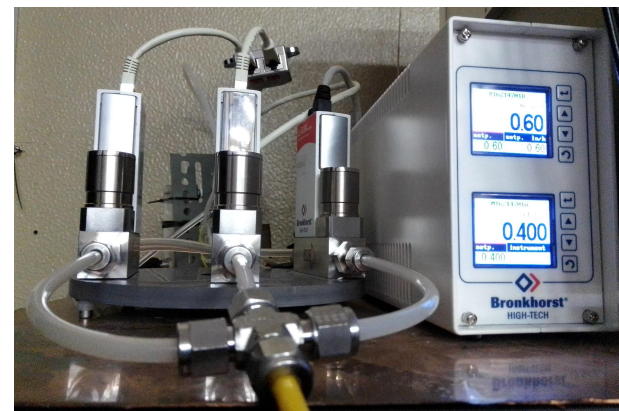
- **Reduced errors in the gas percentages**
by going from 1 L/h to 4 L/h.
- **Maintained He/CF₄ ratio in all measurements**
by keeping He/CF₄ flowing at 60/40 and then adding the required % of isobutane (1% - 5%).

Before, the He/CF₄ ratio was not constant:

	0% isobutane	2% isobutane	5% isobutane
He/CF ₄ /isobutane	60/40	58/40/2	58/37/5
He/CF ₄ ratio	1.5	1.45	~1.57



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Gas flow controllers.

Results He/CF_4 (60/40) + isobutane

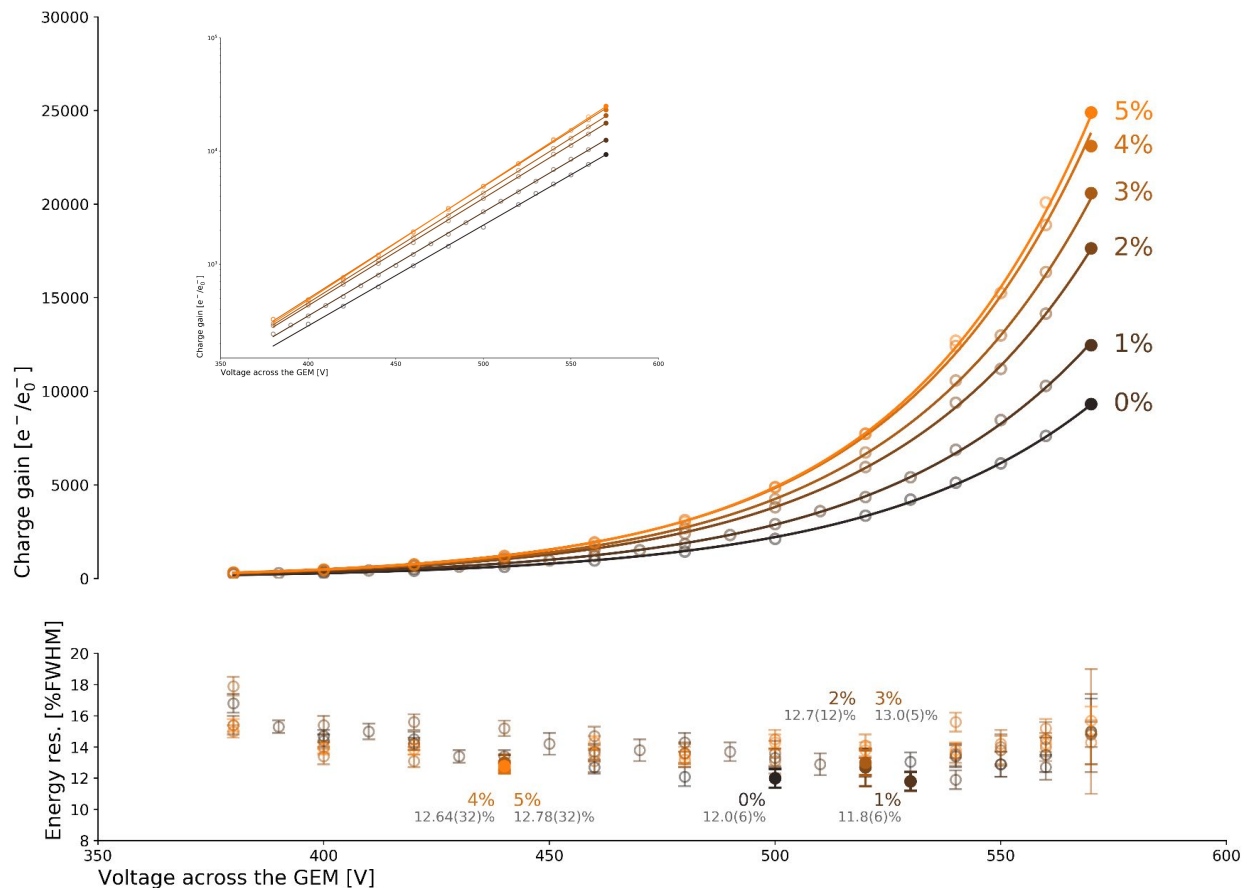
Charge Signals

Charge gain increases with isobutane content

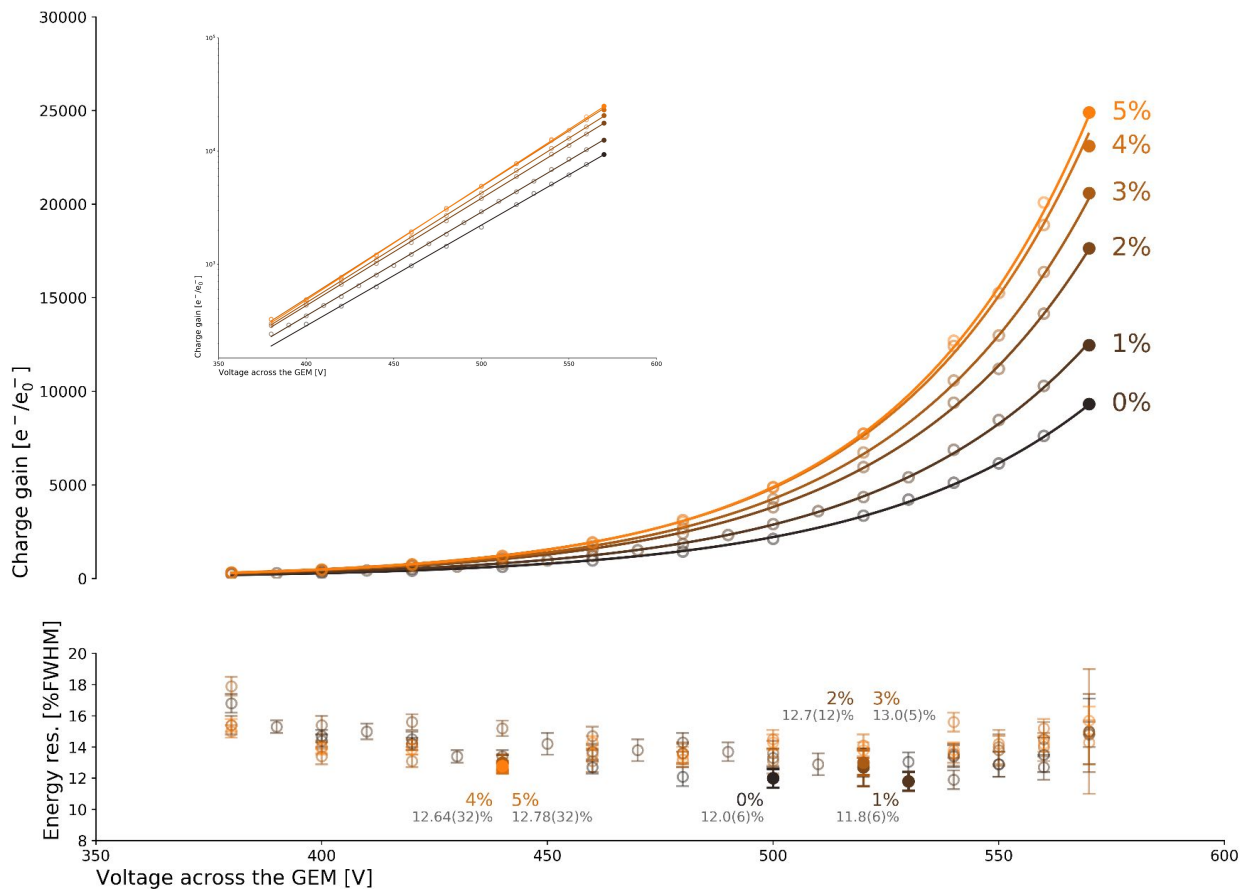
We attribute this behavior to *Penning Transfers*: the energy stored in He metastable states (19.8 eV and 20.6 eV) ionizes isobutane molecules (10.67 eV), thus creating more electron-ion pairs.

For more information:

- "Penning Transfers", by O. Sahin (2008)
- [I Korolov et al 2020 I. Phys. D: Appl. Phys. 53 185201](#)



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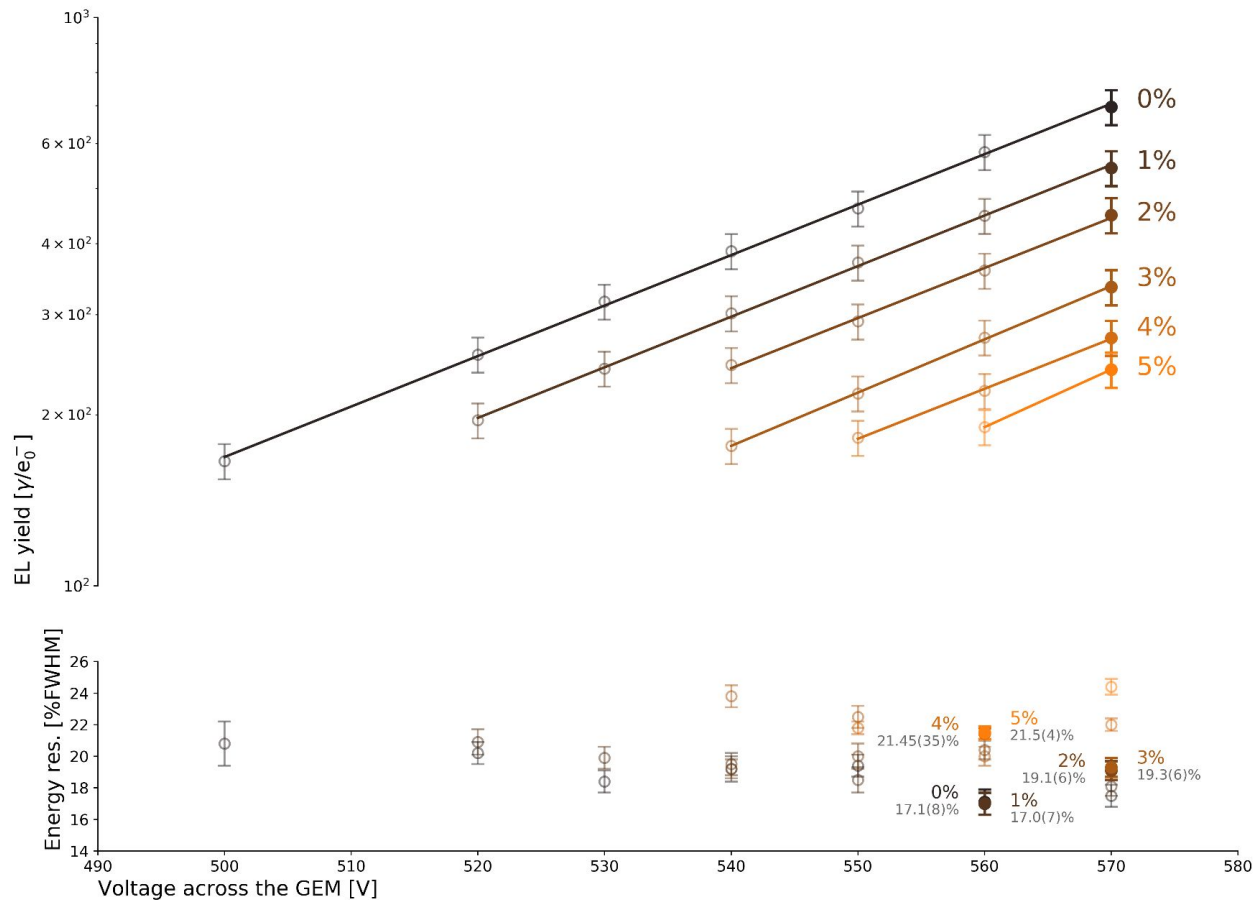
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Energy resolution does not depend on the isobutane content

All studied mixtures had an energy resolution (FWHM) around 12%.

Results He/CF_4 (60/40) + isobutane

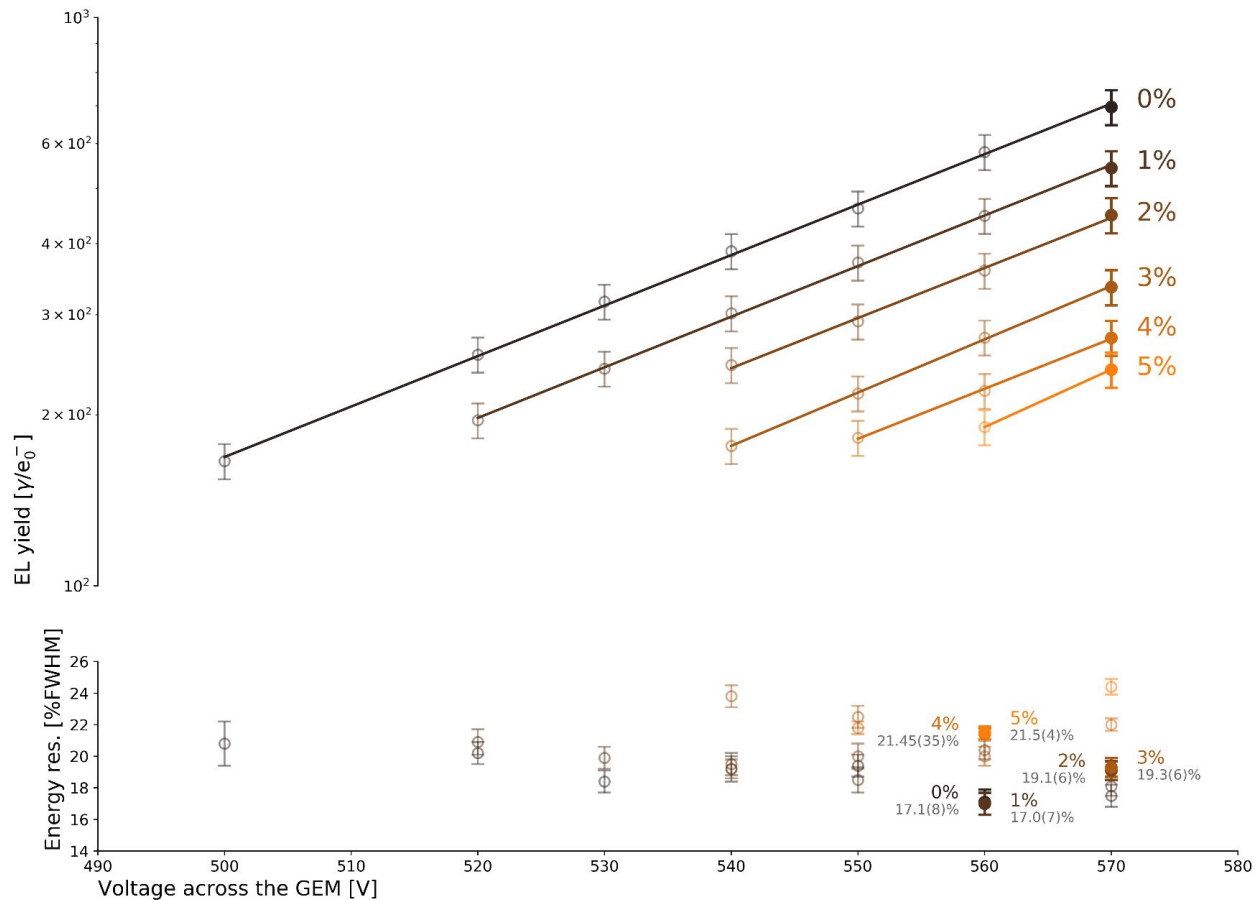


Absolute EL yield

Absolute EL yield decreases with isobutane content

The number of EL photons emitted per primary electron decreases with the concentration of isobutane: isobutane converts EL photons into vibrational and rotational states.

Results He/CF_4 (60/40) + isobutane



Absolute EL yield

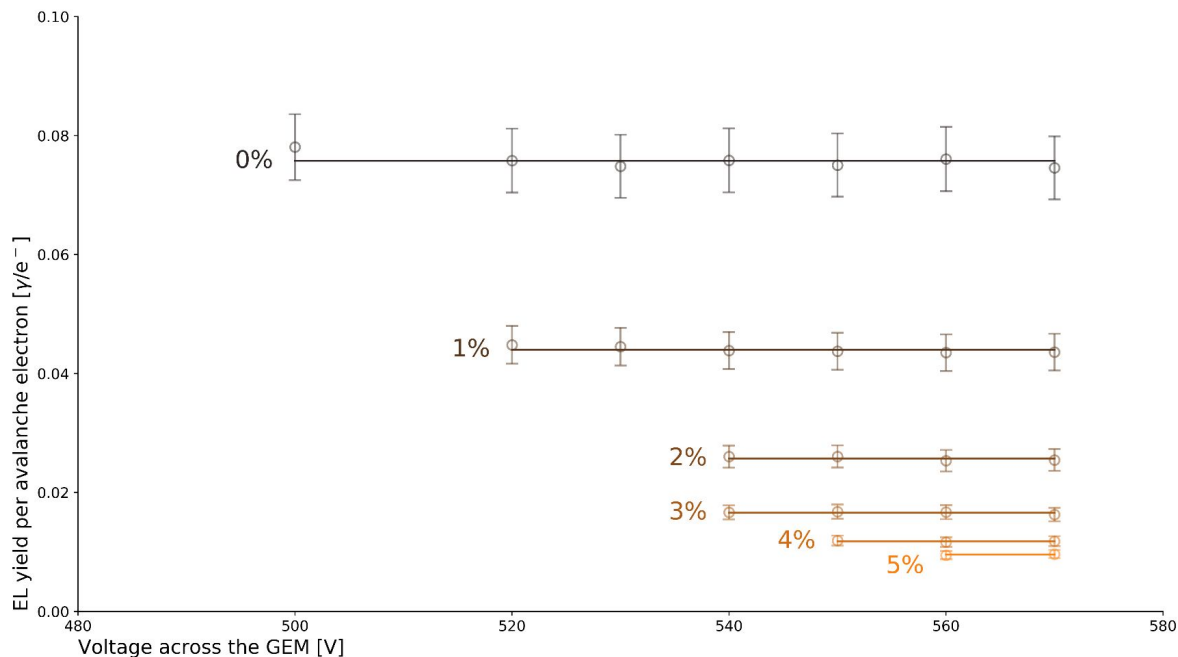
Absolute EL yield decreases with isobutane content

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Energy resolution does not depend on the isobutane content

The gradual degradation in energy resolution is attributed to low statistics and not to decreased detector performance.

Results He/CF_4 (60/40) + isobutane



EL yield per avalanche electron

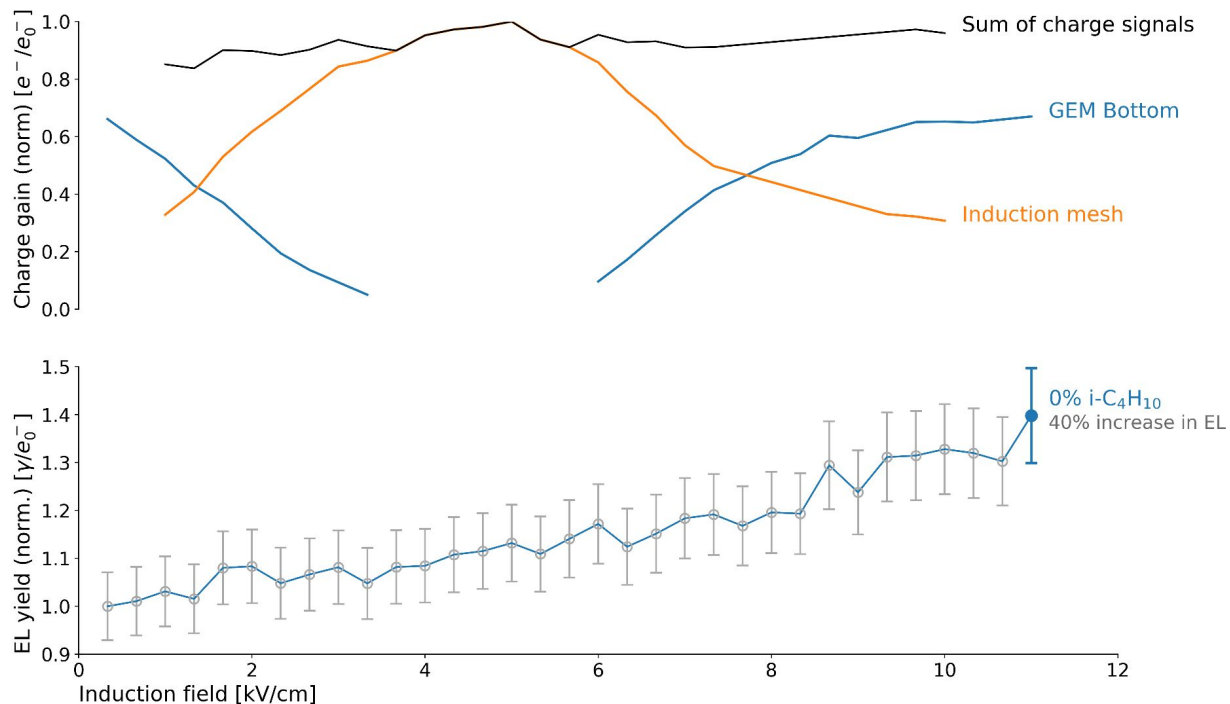
EL yield per avalanche electron decreases with isobutane content

The number of EL photons emitted per avalanche electron decreases with the concentration of isobutane: this is a combination of the *Penning effect* (increased charge gain) and EL decrease (quenching).

% Isobutane	0%	1%	2%	3%	4%	5%
Average EL photons per avalanche electron	0.0757(12)	0.0440(5)	0.0257(4)	0.0166(21)	0.0118(14)	0.00956(14)

Results He/CF_4 (60/40)

Conditions: The voltage across the GEM was kept at 540 V and the induction field was reversed to collect the electrons in the induction mesh.

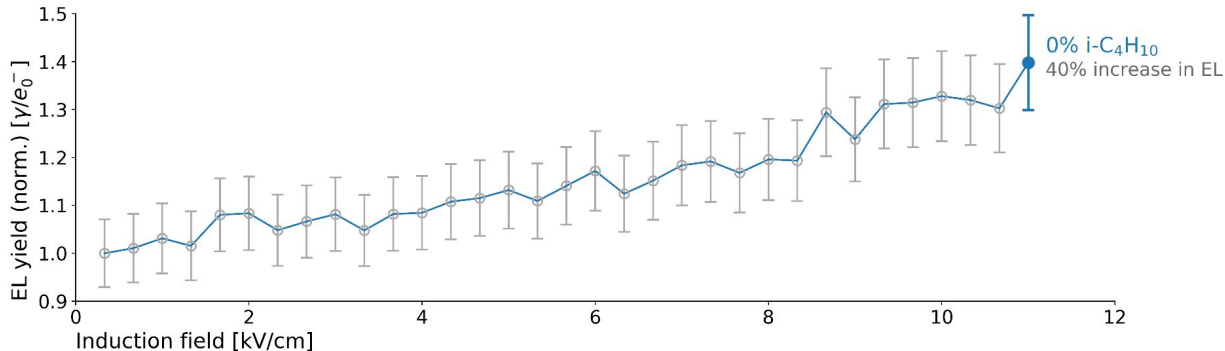
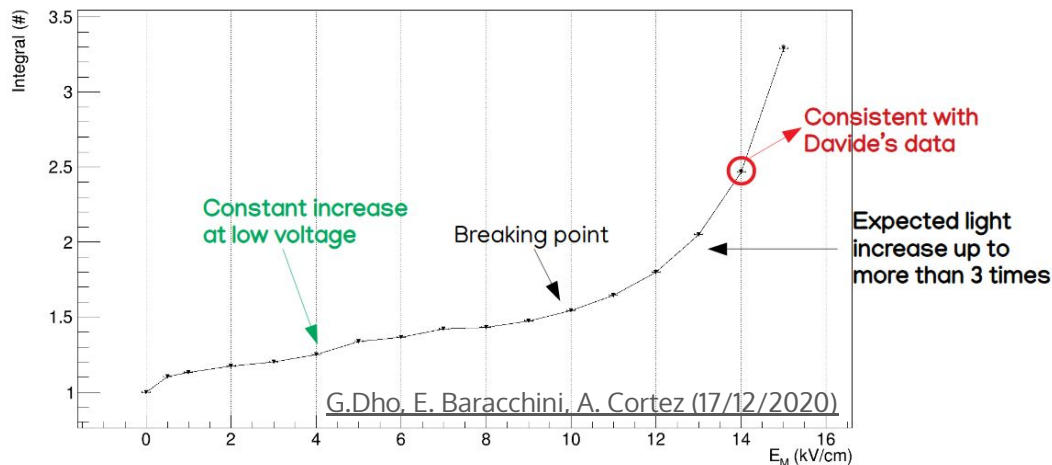


Producing additional EL in the induction region

Irregularities in the charge collection process

For fields above 5 kV/cm, the electrons are not fully collected at the anode: we attribute this effect to the characteristic properties of CF_4 in terms of electron attachment, diffusion and drift velocity (under study).

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We see a 40% increase in absolute EL for 11 kV/cm

We saw a gradual increase in absolute EL, which is consistent with the results reported in the presentation [G.Dho, E. Baracchini, A. Cortez \(17/12/2020\)](#)

Conclusions

With increasing isobutane content:

- Charge gain **increases** due to *Penning Transfers*.
- EL yield **decreases** due to photon quenching.
- Energy resolution **stays unaffected**: ~12% for charge signals and ~20% for EL signals (FWHM @ 5.9 keV).

Conclusions

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Future Work

- **Matching the CYGNO's camera spectral sensitivity** Install the optical glass window to remove the VUV component;
- **Increase the EL yield** Explore other MPGDs with additional amplification regions (MHSP/Cobra_125);
Return to sealed mode operation (using *getters*).

EL yield and charge gain in He/CF₄/isobutane mixtures

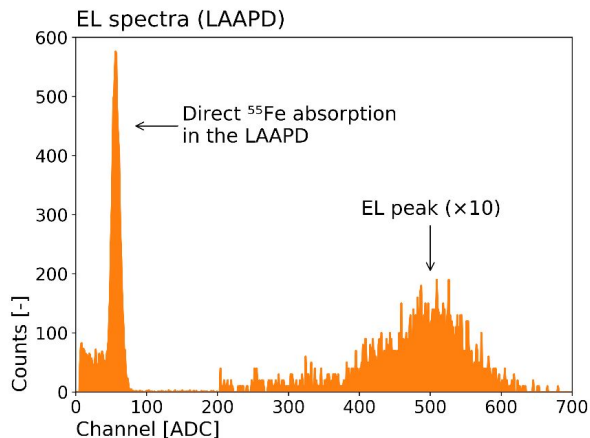
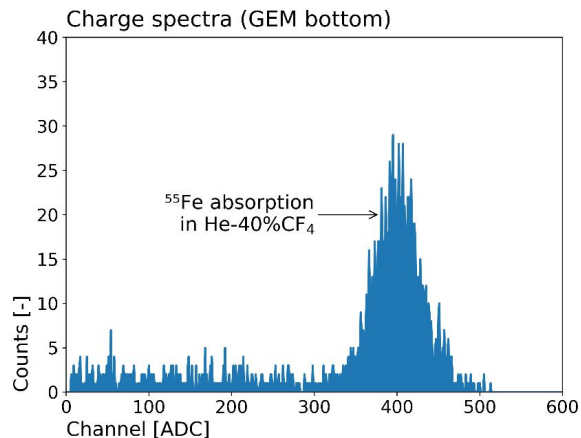


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Grazie per l'attenzione
Any questions?



Backup



EL and ^{55}Fe X-rays
peak ratio

$$Y_{\text{EL}} = \frac{\eta_{\gamma}}{\eta_{e_0^-}} = \frac{w(\text{gas})}{w(\text{Si})} \times \frac{A_{\text{EL}}}{A_{\text{X}}} \times \frac{1}{QE \times \Omega \times T}$$

w -value
(silicon and gas)

quantum efficiency,
solid angle,
mesh transparency

Absolute EL yield

Definition: number of secondary scintillation photons produced in the electron avalanches per primary electron created in the drift region.

The LAAPD detects the direct ^{55}Fe X-rays and the EL photons

The EL peak depends on the EL yield, LAAPD biasing and temperature.

The direct X-ray peak depends only on the LAAPD biasing and temperature.

The direct X-ray peak enables in-spectra calibration and the determination of the absolute EL yield.

For more information:

- [M. Moszyński et al 2002 Nucl. Instr. and Meth. A. 485 504-521](#)
- [C.M.B. Monteiro, PhD Diss. 2011.](#)